RENESAS

ISL80121-5

1A Ultra Low Dropout Linear Regulator with Programmable Current Limiting

FN7713 Rev 6.00 March 21, 2016

DATASHEET

The <u>ISL80121-5</u> is a low dropout voltage, single output LDO with programmable current limiting. The ISL80121-5 operates from input voltages of 5V to 6V with a nominal output voltage of 5V. Other custom voltage options are available upon request.

A submicron BiCMOS process is utilized for this product family to deliver the best in class analog performance and overall value. The programmable current limiting improves system reliability of end applications. An external capacitor on the soft-start pin provides an adjustable soft-starting ramp. The ENABLE feature allows the part to be placed into a low quiescent current shutdown mode.

This BiCMOS LDO will consume significantly lower quiescent current as a function of load compared to bipolar LDOs, which translates into higher efficiency and packages with smaller footprints. Quiescent current is modestly compromised to achieve a very fast load transient response.

TABLE 1. KEY DIFFERENCES BETWEEN FAMILY OF PARTS

| PART NUMBER | PROGRAMMABLE ^I LIMIT | I _{limit} (Default) | ADJ or FIXED V _{OUT} |
|--------------|------------------------------------|---------------------------------|----------------------------------|
| ISL80101-ADJ | No | 1.75A | ADJ |
| ISL80101 | No | 1.75A | 1.8V, 2.5V, 3.3V, 5.0V |
| ISL80101A | Yes | 1.62A | ADJ |
| ISL80121-5 | Yes | 0.75A | 5.0V |

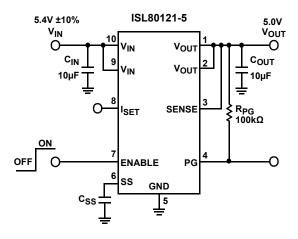
Features

- + $\pm 1.8\%$ V_{OUT} accuracy guaranteed over line, load and T_J = -40 °C to +125 °C
- Very low 130mV dropout voltage
- High accuracy current limit programmable up to 1.75A
- · Very fast transient response
- 210µV_{RMS} output noise
- Power-good output
- Programmable soft-start
- Over-temperature protection
- Small 10 Ld DFN package

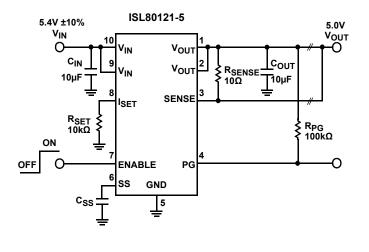
Applications

- USB devices
- Telecommunications and networking
- · Medical equipment
- Instrumentation systems
- · Routers and switchers
- Gaming

Typical Applications



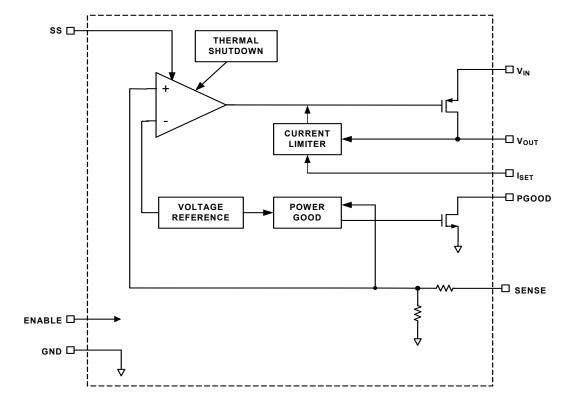




 $I_{\text{LIMIT}} = 0.75 + \frac{2.9}{R_{\text{SET}}(k\Omega)}$ FIGURE 2.



Block Diagram



Ordering Information

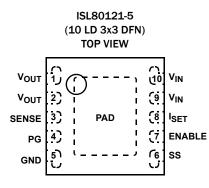
| PART NUMBER (<u>Notes 1, 2, 3</u>) | PART MARKING | V _{OUT} VOLTAGE | TEMP. RANGE (°C) | PACKAGE (RoHS Compliant) | PKG DWG. # |
|---|------------------|--------------------------|---------------------|-----------------------------|---------------|
| ISL80121IR50Z | DZAD | 5.0V | -40 to +125 | 10 Ld 3x3 DFN | L10.3x3 |
| ISL80121-5EVAL2Z | Evaluation Board | | | · | · |

NOTES:

1. Add "-T*" suffix for tape and reel. Please refer to TB347 for details on reel specifications.

- 2. These Intersil Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.
- 3. For Moisture Sensitivity Level (MSL), please see device information page for <u>ISL80121-5</u>. For more information on MSL, please see Technical Brief <u>TB363</u>.

Pin Configuration



Pin Descriptions

| PIN NUMBER | PIN NAME | DESCRIPTION |
|------------|------------------|--|
| 1, 2 | V _{OUT} | Output voltage. A minimum 10µF X5R/X7R output capacitor is required for stability. See <u>"External Capacitor</u> <u>Requirements" on page 9</u> for more details. |
| 3 | SENSE | Remote voltage sense for internally fixed V_{OUT} options. Parasitic resistance between the V_{OUT} pin and the load causes small voltage drops, which degrade V_{OUT} accuracy. For applications that require a stiff V_{OUT} , connect the sense pin to the load. |
| 4 | PG | V _{OUT} in regulation signal. Logic low indicates V _{OUT} is not in regulation, and must be grounded if not used. |
| 5 | GND | Ground. |
| 6 | SS | External capacitor adjusts inrush current. |
| 7 | ENABLE | V _{IN} -independent chip enable. TTL and CMOS compatible. |
| 8 | ISET | Current limit setting. Current limit is 0.75A when this pin is left floating. This default value can be increased by tying R _{SET} to GND, or decreased by tying R _{SET} to V _{IN} . See <u>"Programmable Current Limit" on page 8</u> for more details. Do not short this pin to ground. |
| 9, 10 | V _{IN} | Input supply. A minimum of 10µF X5R/X7R input capacitor is required for stability. See <u>"External Capacitor</u> <u>Requirements" on page 9</u> for more details. |
| - | EPAD | EPAD at ground potential. Soldering it directly to GND plane is required for thermal considerations. See <u>"Power</u> <u>Dissipation and Thermals" on page 9</u> for more details. |



Absolute Maximum Ratings (<u>Note 6</u>)

| V _{IN} Relative to GND0.3V to +6.5V | ۷ |
|---|---|
| V _{OUT} Relative to GND0.3V to +6.5V | V |
| PG, ENABLE, SENSE, SS, I _{SET} | |
| Relative to GND | V |
| ESD Rating | |
| Human Body Model (Tested per JESD22-A114) | V |
| Machine Model (Tested per JESD22-A115) 250V | V |
| Latch-up (Tested per JESD78)±100mA at +125°C | С |

Thermal Information

| Thermal Resistance (Typical) | θ_{JA} (°C/W) | θ _{JC} (°C/W) |
|---|----------------------|------------------------|
| 10 Ld 3x3 DFN Package (<u>Notes 4</u> , <u>5</u>) | 48 | 7 |
| Maximum Junction Temperature (Plastic Pac | kage) | +150°C |
| Storage Temperature Range | 6 | 5°C to +150°C |
| Pb-Free Reflow Profile | | see <u>TB493</u> |

Recommended Operating Conditions (Note 7)

| Junction Temperature Range (T _J) | 40°C to +125°C |
|--|------------------|
| V _{IN} Relative to GND | 5V to 6V |
| ISET in Normal Operation | ≤500mV |
| SENSE in Normal Operation | V _{OUT} |
| PG Sink Current | 10mA |

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

NOTES:

- 4. θ_{JA} is measured in free air with the component mounted on a high effective thermal conductivity test board with "direct attach" features. See Tech Brief <u>TB379</u>.
- 5. For θ_{JC} , the "case temp" location is the center of the exposed metal pad on the package underside.
- 6. Absolute maximum voltage rating is defined as the voltage applied for a lifetime average duty cycle above 6V of 1%.
- 7. Electromigration specification defined as lifetime average junction temperature of +110°C where max rated DC current = lifetime average current.

Electrical Specifications Unless otherwise noted, all parameters are established over the following specified conditions: $V_{IN} = 5.4V$, $V_{OUT} = 5.0V$, $T_J = +25$ °C, $I_{LOAD} = 0A$. Applications must follow thermal guidelines of the package to determine worst case junction temperature. Please refer to <u>"Functional Description" on page 8</u> and Tech Brief <u>TB379</u>.

Boldface limits apply across the operating temperature range, -40°C to +125°C. Pulse load techniques used by ATE to ensure $T_J = T_A$ defines established limits.

| PARAMETER | SYMBOL | TEST CONDITIONS | MIN (<u>Note 8</u>) | ТҮР | MAX (<u>Note 8</u>) | UNITS |
|-----------------------------------|---|---|--------------------------|------|--------------------------|-------|
| DC CHARACTERISTICS | | | | | | |
| DC Output Voltage Accuracy | V _{OUT} | 5.4V < V _{IN} < 6V; 0A < I _{LOAD} < 1A | -1.8 | | 1.8 | % |
| DC Input Line Regulation | (V _{OUT} low line - V _{OUT} high line)/V _{OUT} low line | 5.4V < V _{IN} < 6V, V _{OUT} = 5V | -1 | | 1 | % |
| DC Output Load Regulation | (V _{OUT} no load - V _{OUT} high load)/V _{OUT} no load | 0A < I _{LOAD} < 1A | -1 | | 1 | % |
| Ground Pin Current | lq | I _{LOAD} = 0A, 5.4V < V _{IN} < 6V | | 3 | 5 | mA |
| | | I _{LOAD} = 1A, 5.4V < V _{IN} < 6V | | 5 | 7 | mA |
| Ground Pin Current in Shutdown | I _{SHDN} | ENABLE = 0.2V, V _{IN} = 6V | | 0.2 | 12 | μA |
| Dropout Voltage (<u>Note 9</u>) | V _{DO} | I _{LOAD} = 1A, V _{SENSE} = 0V | | 90 | 130 | mV |
| Output Current Limit | ILIMIT | 5.4V < V _{IN} < 6V, I _{SET} is floating | 0.66 | 0.75 | 0.84 | Α |
| | | 5.4V < V _{IN} < 6V, R _{SET} = 19.33kΩ | | 0.9 | | Α |
| Thermal Shutdown Temperature | TSD | 5.4V < V _{IN} < 6V | | 160 | | °C |
| Thermal Shutdown Hysteresis | TSDn | 5.4V < V _{IN} < 6V | | 30 | | °C |

Electrical Specifications Unless otherwise noted, all parameters are established over the following specified conditions: $V_{IN} = 5.4V$, $V_{OUT} = 5.0V$, $T_J = +25$ °C, $I_{LOAD} = 0A$. Applications must follow thermal guidelines of the package to determine worst case junction temperature. Please refer to <u>"Functional Description" on page 8</u> and Tech Brief <u>TB379</u>.

Boldface limits apply across the operating temperature range, -40 °C to +125 °C. Pulse load techniques used by ATE to ensure $T_J = T_A$ defines established limits. (Continued)

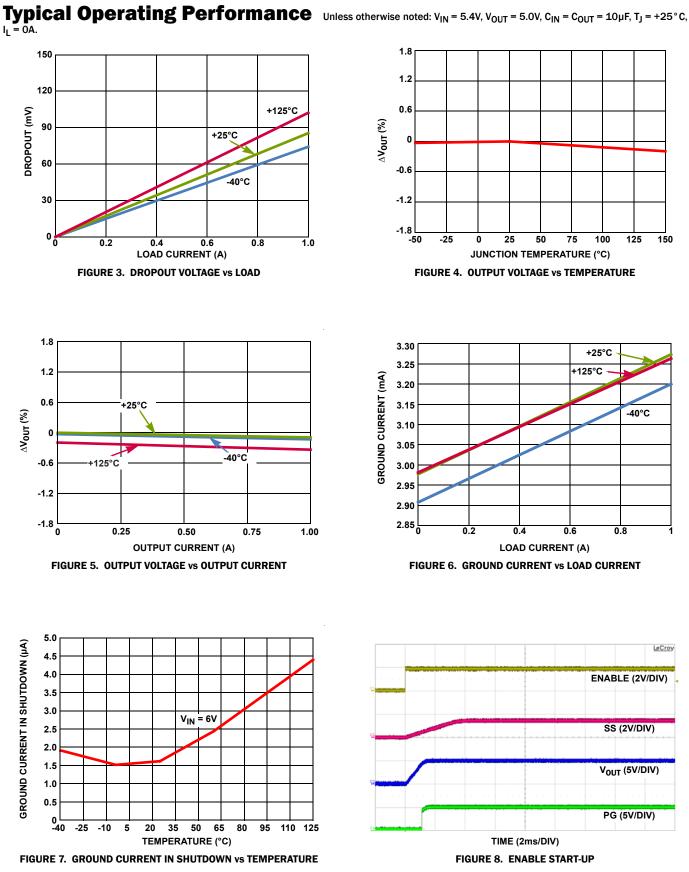
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN (<u>Note 8</u>) | ТҮР | MAX (<u>Note 8</u>) | UNITS |
|-------------------------------------|-----------------------|--|--------------------------|------|--------------------------|-------------------|
| AC CHARACTERISTICS | | | | | | |
| Input Supply Ripple Rejection | PSRR | f = 1kHz, I _{LOAD} = 1A | | 40 | | dB |
| | | f = 1kHz, I _{LOAD} = 100mA | | 40 | | dB |
| Output Noise Voltage | | I _{LOAD} = 10mA, BW = 10Hz < f < 100kHz | | 210 | | μV _{RMS} |
| ENABLE PIN CHARACTERISTICS | | | | | | |
| Turn-on Threshold | V _{EN(HIGH)} | 5.4V < V _{IN} < 6V | 0.5 | 0.8 | 1.0 | v |
| Hysteresis | V _{EN(HYS)} | 5.4V < V _{IN} < 6V | 10 | 80 | 200 | mV |
| ENABLE Pin Turn-on Delay | t _{EN} | $C_{OUT} = 10 \mu F, I_{LOAD} = 1A$ | | 100 | | μs |
| ENABLE Pin Leakage Current | | V _{IN} = 6V, ENABLE = 3V | | | 1 | μA |
| SOFT-START CHARACTERISTICS | | | ł | | | |
| Reset Pull-down Current | I _{PD} | ENABLE = OV, SS = 1V | 0.5 | 1 | 1.3 | mA |
| Soft-start Charge Current | I _{CHG} | | -3.3 | -2 | -0.8 | μA |
| PG PIN CHARACTERISTICS | | | ł | | | |
| V _{OUT} PG Flag Threshold | | | 75 | 84 | 92 | %V _{OUT} |
| V _{OUT} PG Flag Hysteresis | | | | 4 | | % |
| PG Flag Low Voltage | | I _{SINK} = 500μA | | 47 | 100 | mV |
| PG Flag Leakage Current | | V _{IN} = 6V, PG = 6V | | 0.05 | 1 | μA |

NOTES:

8. Compliance to data sheet limits is assured by one or more methods: production test, characterization and/or design.

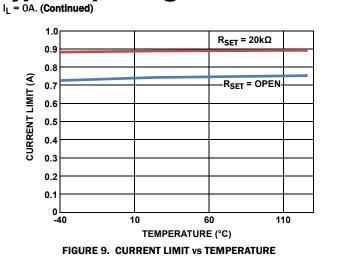
9. Dropout is defined by the difference in supply V_{IN} and V_{OUT} when the output is below its nominal regulation.

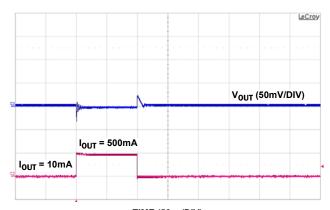






Typical Operating Performance Unless otherwise noted: $V_{IN} = 5.4V$, $V_{OUT} = 5.0V$, $C_{IN} = C_{OUT} = 10\mu$ F, $T_J = +25^{\circ}$ C,





TIME (50µs/DIV) FIGURE 10. LOAD TRANSIENT RESPONSE

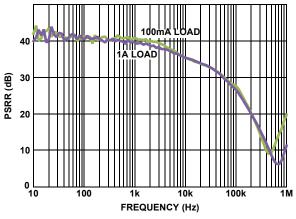
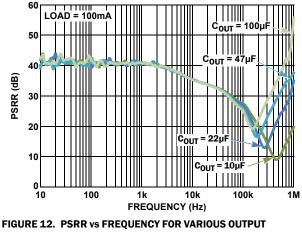
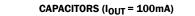


FIGURE 11. PSRR vs FREQUENCY FOR VARIOUS LOAD CURRENTS





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Functional Description

Input Voltage Requirements

The ISL80121-5 is optimized for 5V output, and can operate from input voltages of 5V to 6V. Due to the nature of an LDO, $V_{\rm IN}$ must be some margin higher than $V_{\rm OUT}$ plus dropout at the maximum rated current of the application if active filtering (PSRR) is expected from $V_{\rm IN}$ to $V_{\rm OUT}$. The generous dropout specification of this family of LDOs allows applications to design for a level of efficiency.

Programmable Current Limit

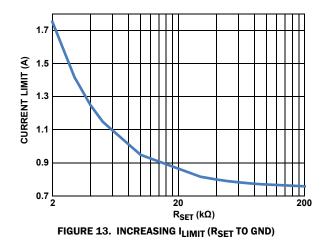
The ISL80121-5 protects against overcurrent due to short-circuit and overload conditions applied to the output. When this happens, the LDO performs as a constant current source. If the short-circuit or overload condition is removed, the output returns to normal voltage regulation operation.

The current limit is set at 0.75A by default when the $\ensuremath{\mathsf{I}_{\text{SET}}}$ pin is left floating.

This limit can be increased by tying a resistor R_{SET} from the I_{SET} pin to ground. The current limit is determined by R_{SET} as shown in Equation 1:

$$I_{L1M1T} = 0.75 + \frac{2.9}{R_{SET}(k\Omega)}$$
(EQ. 1)

Figure 13 shows the relationship between R_{SET} and the current limit when the R_{SET} is tied from I_{SET} pin to GND. Do not short this pin to ground. Increasing the current limit past 1.75A may cause damage to the part and is highly discouraged.



The current limit can be decreased from the 0.75A default by tying R_{SET} from the I_{SET} pin to V_{IN}. The current limit is then determined by both R_{SET} and V_{IN} following Equation 2:

$$I_{\text{LIMIT}} = 0.75 - \frac{2.9 \times (2 \times V_{\text{IN}} - 1)}{R_{\text{SET}}(k\Omega)}$$
(EQ. 2)

Figure 14 shows the relationship between R_{SET} and the current limit when R_{SET} is tied from the I_{SET} pin to V_{IN} for $V_{IN} = 5.4V$.

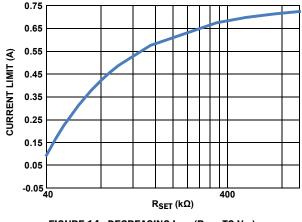


FIGURE 14. DECREASING ISET (RSET TO VIN)

Enable Operation

The ENABLE turn-on threshold is typically 800mV with 80mV of hysteresis. An internal pull-up or pull-down resistor to change these values is available upon request. As a result, this pin must not be left floating and should be tied to V_{IN} if not used. A $1 \text{k} \Omega$ to $10 \text{k} \Omega$ pull-up resistor is required for applications that use open collector or open-drain outputs to control the ENABLE pin. The ENABLE pin may be connected directly to V_{IN} for applications with outputs that are always on.

Power-good Operation

PG is a logic output that indicates the status of V_{OUT}. The PG flag is an open-drain NMOS that can sink up to 10mA during a fault condition. The PG pin requires an external pull-up resistor typically connected to the V_{OUT} pin. The PG pin should not be pulled up to a voltage source greater than V_{IN}. PG goes low when the output voltage drops below 84% of the nominal output voltage, the current limit faults, or the input voltage is too low. For applications not using this feature, connect this pin to ground.

Soft-start Operation

The soft-start circuit controls the rate at which the output voltage rises up to regulation at power-up or LDO enable. This start-up ramp time can be set by adding an external capacitor from the SS pin to ground. An internal 2µA current source charges up this C_{SS} and the feedback reference voltage is clamped to the voltage across it. The start-up time is set by Equation 3:

$$t_{start} = \frac{(C_{SS} x 0.5)}{2\mu A}$$
(EQ. 3)

<u>Equation 4</u> determines the C_{SS} required for a specific start-up inrush current, where V_{OUT} is the output voltage, C_{OUT} is the total capacitance on the output and I_{INRUSH} is the desired inrush current.

$$C_{SS} = \frac{(V_{OUT} x C_{OUT} x 2 \mu A)}{I_{INRUSH} x 0.5 V}$$
(EQ. 4)

The external capacitor is always discharged to ground at the beginning of start-up or enabling.



External Capacitor Requirements

External capacitors are required for proper operation. Careful attention must be paid to the layout guidelines and selection of capacitor type and value to ensure optimal performance.

OUTPUT CAPACITOR

The ISL80121-5 applies state-of-the-art internal compensation to keep the selection of the output capacitor simple for the customer. Stable operation over full temperature, V_{IN} range, V_{OUT} range and load extremes are guaranteed for all capacitor types and values assuming a minimum of 10µF X5R/X7R is used for local bypass on V_{OUT} . This output capacitor must be connected to the V_{OUT} and GND pins of the LDO with PCB traces no longer than 0.5cm.

There is a growing trend to use very low ESR multilayer ceramic capacitors (MLCC) because they can support fast load transients and also bypass very high frequency noise from other sources. However, the effective capacitance of MLCCs drops with applied voltage, age and temperature. X7R and X5R dieletric ceramic capacitors are strongly recommended as they typically maintain a capacitance range within $\pm 20\%$ of nominal voltage over full operating ratings of temperature and voltage.

Additional capacitors of any value in ceramic, POSCAP, alum/tantalum electrolytic types may be placed in parallel to improve PSRR at higher frequencies and/or load transient AC output voltage tolerances.

INPUT CAPACITOR

For proper operation, a minimum capacitance of 10 μ F X5R/X7R is required at the input. This ceramic input capacitor must be connected to the V_{IN} and GND pins of the LDO with PCB traces no longer than 0.5cm.

Power Dissipation and Thermals

The junction temperature must not exceed the range specified in the <u>"Recommended Operating Conditions (Note 7)" on page 4</u>. The power dissipation can be calculated by using <u>Equation 5</u>:

$$P_{D} = (V_{IN} - V_{OUT}) \times I_{OUT} + V_{IN} \times I_{GND}$$
(EQ. 5)

The maximum allowable junction temperature, $T_{J(MAX)}$ and the maximum expected ambient temperature, $T_{A(MAX)}$ determine the maximum allowable power dissipation, as shown in Equation 6:

$$\mathsf{P}_{D(MAX)} = (\mathsf{T}_{J(MAX)} - \mathsf{T}_{A}) / \theta_{JA} \tag{EQ. 6}$$

 θ_{JA} is the junction-to-ambient thermal resistance.

For safe operation, ensure that the power dissipation P_D , calculated from Equation 5, is less than the maximum allowable power dissipation P_D (MAX).

The DFN package uses the copper area on the PCB as a heatsink. The EPAD of this package must be soldered to the copper plane (GND plane). Figure 15 shows a curve for the θ_{JA} of the DFN package for different copper area sizes.

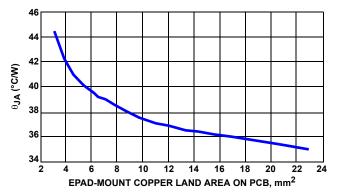


FIGURE 15. 3mm x3mm 10 LD DFN ON 4-LAYER PCB WITH THERMAL VIAS θ_{JA} vs EPAD-MOUNT COPPER LAND AREA ON PCB

Thermal Fault Protection

The power level and the thermal impedance of the package (+48 ° C/W for DFN) determine when the junction temperature exceeds the thermal shutdown temperature. In the event that the die temperature exceeds around +160 ° C, the output of the LDO will shut down until the die temperature cools down to about +130 ° C.

General Power PAD Design Considerations

Figure 16 shows the recommended use of vias on the thermal pad to remove heat from the IC. This typical array populates the thermal pad footprint with vias spaced three times the radius distance from the center of each via. Small via size is advisable, but not to the extent that solder reflow becomes difficult.

All vias should be connected to the pad potential, with low thermal resistance for efficient heat transfer. Complete connection of the plated through-hole to each plane is important. It is not recommended to use "thermal relief" patterns to connect the vias.

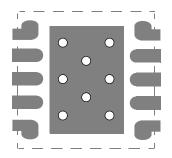


FIGURE 16. PCB VIA PATTERN



Revision History The revision history provided is for informational purposes only and is believed to be accurate, but not warranted. Please go to web to make sure you have the latest revision.

| DATE | REVISION | CHANGE |
|-----------------------|----------|---|
| March 21, 2016 | FN7713.6 | On page 1 -Under Features, changed "Very low 130mV dropout voltage at V _{IN} = 5V" to "Very low 130mV dropout voltage". -Updated Figures 1 and 2 by removing ±1.8%. -Updated Block Diagram" on page 2. -On page 4, updated latch-up condition from +85C to +125C. -In Electrical Specifications table updated the following: -Heading -DC Output Voltage Accuracy Test Condition -DC Input Line Regulation Spec/Symbol -Ground Pin Current Test Condition -DC Output Load Regulation Spec/Symbol -Ground Pin Current Test Condition -Dropout Voltage Test Condition -Dropout Voltage Test Condition -Dropout Voltage Test Condition -Thermal Shutdown Hysteresis Test Condition -Thermal Shutdown Hysteresis Test Condition -Turn-on Threshold Test Condition -Turn-on Threshold Test Condition -Updated y-Axis and titles of Figure 7 on page 6. -Updated Y-Axis labels and titles of Figures 11 and 12 on page 7. -Removed "that can accommodate profiles smaller than the TO220/263" from last sentence of paragraph under "Input Voltage Requirements" on page 8. -Removed "PG functions during shutdown, but not during thermal shutdown." from "Power-good Operation" on page 8. -Removed "PG functions during shutdown, but not during thermal shutdown." from "Power-good Operation" on page 8. -Renoved "PG functions during shutdown, but not during thermal shutdown." from "Power-good Operation" on page 8. -Renoved "PG functions during shutdown, but not during thermal shutdown." from "Power-good Operation" on page 8. -Renoved "PG functions during shutdown, but not during thermal shutdown." from "Power-good Operation" on page 8. -Renoved "PG functions during shutdown intersil section. -Updated POD to the latest revision changes are listed below: -Rev. 7 to Rev. 8 "Corrected L-shaped leads in Bottom view and land pattern so that they align with the rest of the leads (L shaped leads were shorter)" -Rev. 8 to Rev. 9, "Added missing dimension 0.415 in Typical Recommended land pattern". -Rev. 9 to Rev. 10 "Shortened the e-pad rectangle on |
| June 22, 2012 | FN7713.5 | Tiebar shown (if present) is a non-functional feature and may be located on any of the 4 sides (or ends)." 1. Changed POD L10.3X3 on page 12 to latest revision from 6 to 7. Change POD is as follows: Removed package outline and included center to center distance between lands on recommended land pattern. Removed Note 4 "Dimension b applies to the metalized terminal and is measured between 0.18mm and 0.30mm from the terminal tip." since it is not applicable to this package. Renumbered notes accordingly. 2. "Input Voltage Requirements" on page 8 changed input voltages from "2.2V" to "5V" 3. Page 1: On 3rd paragraphs first sentence "CMOS" changed to "BiCMOS". 4. Page1: 1st paragraph sentence changed from: "This LDO operates from input voltages of 2.2V to 6V. The ISL80121-5 has a nominal output voltage of 5V". TO: "The ISL80121-5 operates from input voltages of 5V |
| | | to 6V with a nominal output voltage of 5V". 5. Page 2: Removed Note in Ordering Information: "The 1.5V, 3.3V and 5V fixed output voltages will be released in the future. Please contact Intersil Marketing for more details". 6. Page 4: Recommended Operation Conditions "V_{In} relative to GND changed from 2.2V to 6V to 5V to 6V" |
| September 29, 2011 | FN7713.4 | 7. Page 4: Recommended Operation Conditions Removed "V_{out} Range line 800mV T0 5V" Table 1 on page 1 updated to include more information on Intersil's 1A LDO portfolio. |
| April 22, 2011 | FN7713.3 | In Figure 10 on page 7, corrected label from "V _{OUT} (50V/DIV)." to "V _{OUT} (50mV/DIV)." In "DC Output Voltage Accuracy" on page 4, corrected the MAX value from -1.8 to +1.8. |



Revision History The revision history provided is for informational purposes only and is believed to be accurate, but not warranted. Please go to web to make sure you have the latest revision. (Continued)

| DATE | REVISION | CHANGE |
|-------------------|----------|--|
| February 24, 2011 | FN7713.2 | page 1, paragraph 2, "The programmable current limiting improves system reliability of applications" changed to "The programmable current limiting improves system reliability of end applications." |
| | | 2. page 1, Features, "Programmable Soft-starting" changed to "Programmable Soft-Start" |
| | | 3. Made subbing consistent throughout document. |
| | | 4. page 3, EPAD Description "directly to GND plane is optional." Changed to "directly to GND plane is required for thermal considerations. See "Power Dissipation and Thermals" on page 9 for more details." |
| | | 5. page 5, Removed Notes in Electrical Spec Table, which read: "Minimum capacitor of 10μF X5R/X7R on V _{IN} and V _{OUT} required for stability." and "If the current limit for inrush current is acceptable in application, do not use this feature. Used only when large bulk capacitance required on V _{OUT} for application." |
| | | page 5, Electrical Specifications, PG Pin Characteristics, V_{out} PG Flag Threshold a.Typical "85" changed to "84" %V_{out} |
| | | 7. page 9, after Thermal Fault Protection section a.Added "General Power PAD Design Considerations" section with Figure 14. |
| | | 8. All PGOOD changed to PG throughout. |
| | | 9. Changed Theta Ja from 51C/W to 48C/W. |
| | | 1.page 1, Features a."200μVrms Output Noise" changed to "210 μVrms Output Noise" 2.page 1, Typical Applications, right side figure a.Resize "V_{OUT}" (pin2) and "SENSE" (pin3) 3.page 8, Equation 4 a.Extra parenthesis ")" removed |
| | | page 1 Before Features added Table of Key Differences. page 2 Block Diagram - Removed "ADJ Voltage Version" and left the "Sense" Connection. page 3 Pin Number 8, description, 2nd sentence: "Current limit is 0.75mA" changed to "Current limit is 0.75A" page 5 Electrical Specifications, AC Characteristics, Input Supply Ripple Rejection Test conditions and Typical values changed from "f = 1kHz, ILOAD = 1A, f = 120Hz, ILOAD = 1A" TO "f = 1kHz, ILOAD = 1A, f = 1kHz, ILOAD = 100mA" page 6, Figure 5 - X-axis label changed from "Output Current (mA)" to "Output Current (A) |
| | | page 8, Figure 14 - a.Figure label change. "IN" in "V _{IN} " was subscripted. |
| December 6, 2010 | FN7713.1 | In "Block Diagram" on page 2: a. Added "ADJ adjustable voltage version" Pin. Added "fixed voltage version" to "SENSE" pin On page 4: "Ground Pin Current" Test Conditions a. Replaced "V_{OUT}+0.4V" with "2.2V" on both lines |
| December 2, 2010 | FN7713.0 | Initial Release. |

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